

SP712 Series 640W Asymmetrical TVS Diode Array

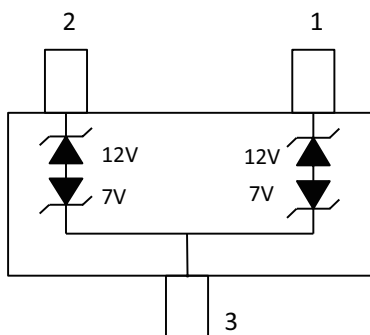


Description

The SP712 TVS Diode Array is designed to protect RS-485 applications with asymmetrical working voltages (-7V to 12V) from damage due to electrostatic discharge (ESD), electrical fast transients (EFT), and lightning induced surges.

The SP712 can absorb repetitive ESD strikes above the maximum level specified in IEC 61000-4-2 international standard without performance degradation and safely dissipate up to 20A of 8/20us induced surge current (IEC 61000-4-5) with very low clamping voltages.

Pinout and Functional Block Diagram



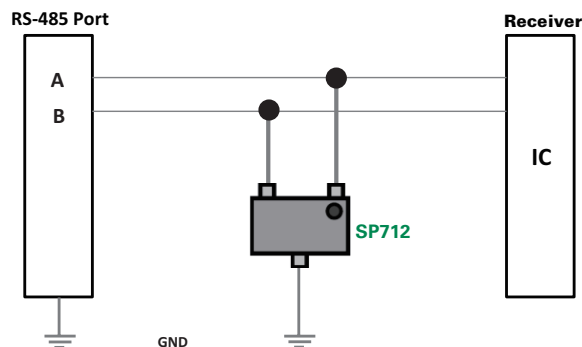
Features

- ESD, IEC 61000-4-2, $\pm 30\text{kV}$ contact, $\pm 30\text{kV}$ air
- EFT, IEC 61000-4-4, 50A (5/50ns)
- Lightning, IEC 61000-4-5 2nd edition, 20A ($t_p=8/20\mu\text{s}$)
- Working Voltages: -7V to 12V
- Low clamping voltage
- Low leakage current
- Halogen free, Lead free and RoHS compliant
- Moisture Sensitivity Level(MSL -1)
- AEC-Q101 qualified

Applications

- RS-485
- Fieldbus
- Modbus
- Profibus
- DMX512
- Security Systems
- Automated Teller Machines (ATMs)
- Lighting Control - DALI
- Communication Equipments

RS-485 Application Example



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

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Absolute Maximum Ratings

Symbol	Parameter	Value	Units
P_{PK}	Peak Pulse Power ($t_p=8/20\mu s$)	640	W
I_{PP}	Peak Pulse Current ($t_p=8/20\mu s$)	20	A
T_{OP}	Operating Temperature	-40 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

Notes:

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

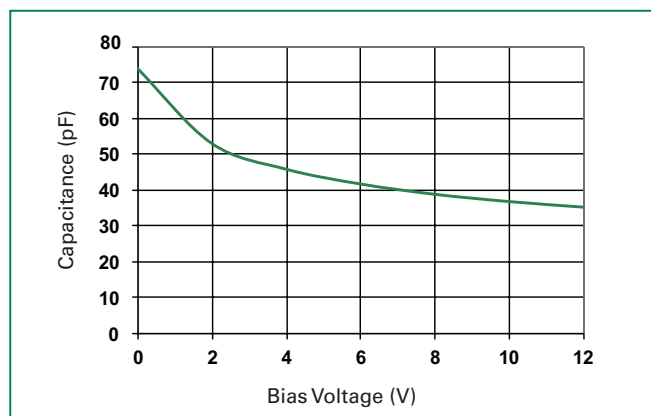
Electrical Characteristics ($T_{OP}=25^{\circ}C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R=1\mu A$, Pin 3 to Pin 1 or Pin 2			7.0	V
		$I_R=1\mu A$, Pin 1 or Pin 2 to Pin 3			12.0	V
Breakdown Voltage	V_{BR}	$I_R=1mA$, Pin 3 to Pin 1 or Pin 2	7.5	9		V
		$I_R=1mA$, Pin 1 or Pin 2 to Pin 3	13.3	14.5		V
Reverse Leakage Current	I_{LEAK}	$V_R=7V$			20	μA
		$V_R=12V$			1	μA
Clamp Voltage ¹	V_C	$I_{PP}=1A$, $t_p=8/20\mu s$, Pin 1 or Pin 2 to Pin 3		17	19	V
		$I_{PP}=1A$, $t_p=8/20\mu s$, Pin 3 to Pin 1 or Pin 2		10	11	V
		$I_{PP}=20A$, $t_p=8/20\mu s$, Pin 1 or Pin 2 to Pin 3		28	32	V
		$I_{PP}=20A$, $t_p=8/20\mu s$, Pin 3 to Pin 1 or Pin 2		17	20	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p=100ns$		0.26		Ω
ESD Withstand Voltage ¹	V_{ESD}	IEC 61000-4-2 (Contact Discharge)	± 30			kV
		IEC 61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, $f=1MHz$; Pin 1 or Pin 2 to Pin 3			75	pF

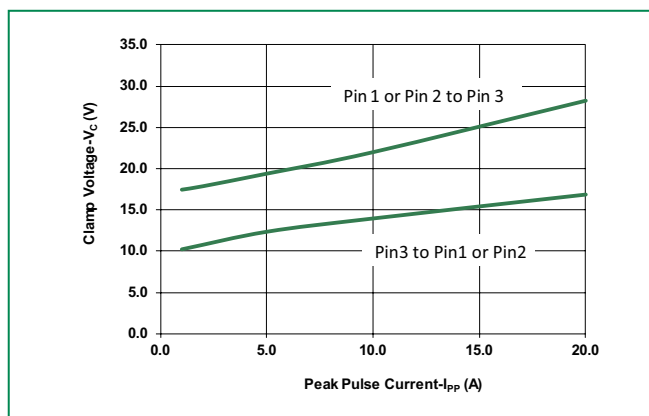
Notes : 1. Parameter is guaranteed by design and/or component characterization.

2. Transmission Line Pulse (TLP) test setting : Std.TDR(50 Ω), $t_p=100ns$, $t_r=0.2ns$ ITLP and VTLP averaging window: start $t_1=70ns$ to end $t_2=90ns$

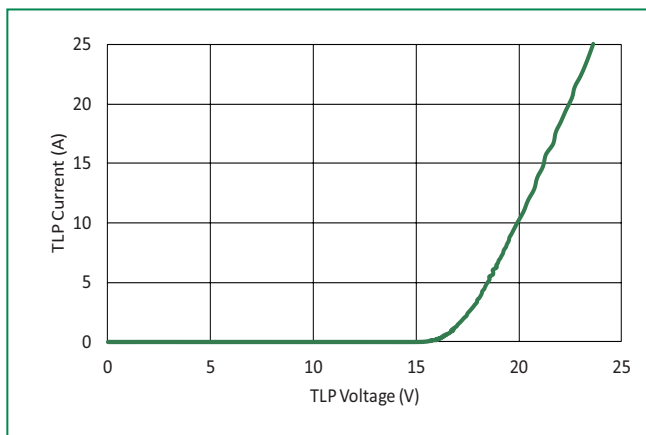
Capacitance vs. Reverse Bias



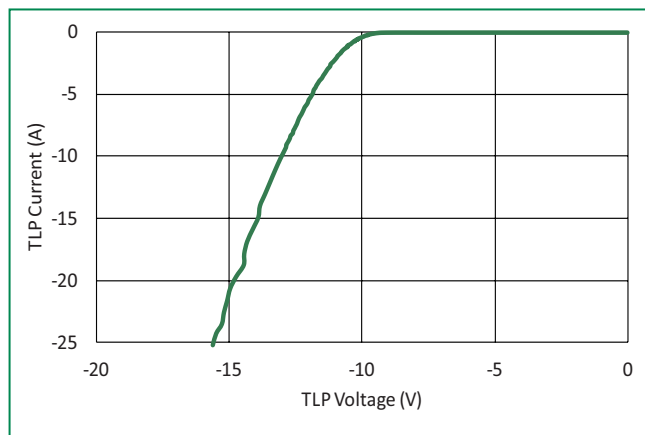
Clamping Voltage vs. I_{PP}



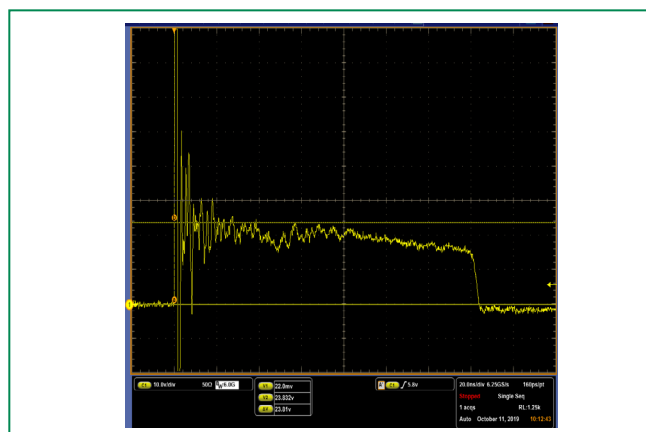
Positive Transmission Line Pulsing (TLP) Plot



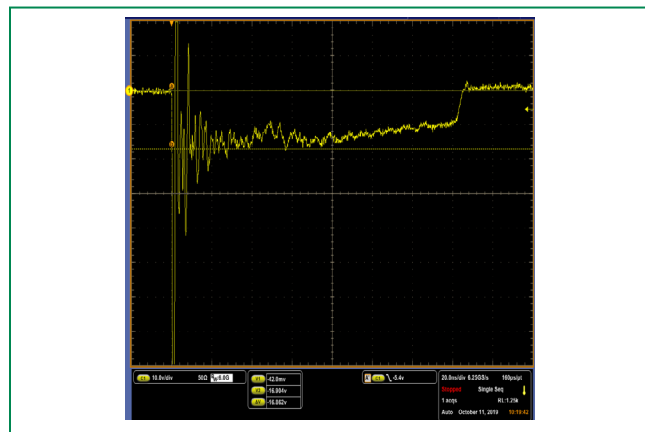
Negative Transmission Line Pulsing (TLP) Plot



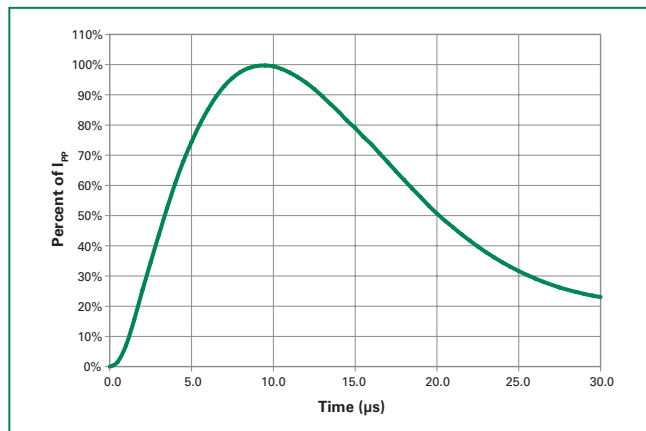
IEC 61000-4-2 +8kV Contact ESD Clamping Voltage



IEC 61000-4-2 -8kV Contact ESD Clamping Voltage

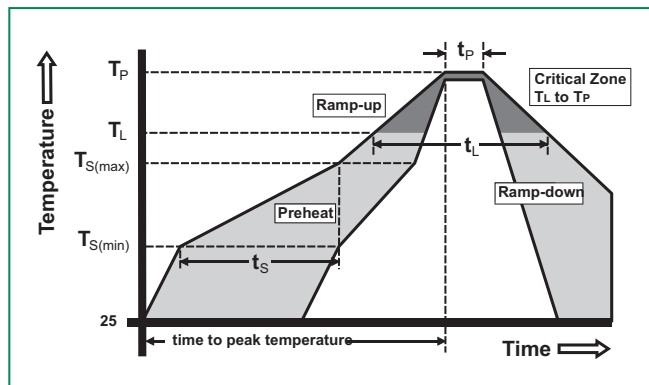


8/20μs Pulse Waveform



Soldering Parameters

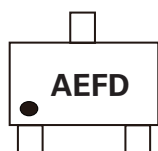
Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



Product Characteristics

Lead Plating	Matte Tin
Lead Material	Copper Alloy
Lead Coplanarity	0.004 inches(0.102mm)
Substrate Material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0

Part Marking System

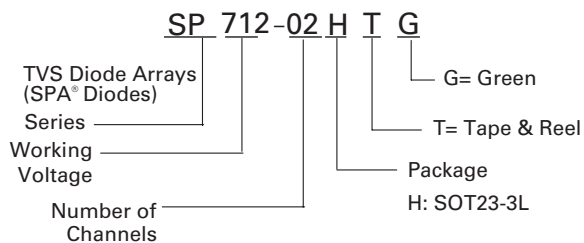


AE : Part code
F : Assembly code
D : Date code

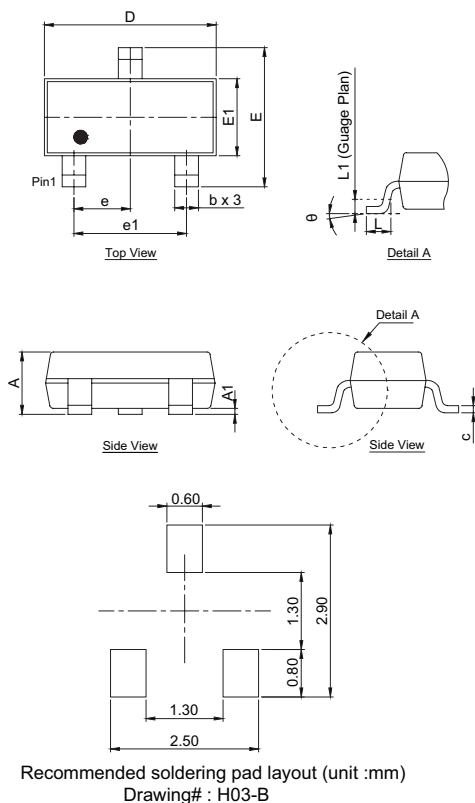
Ordering Information

Part Number	Package	Min. Order Qty.
SP712-02HTG	SOT23-3L	3000

Part Numbering System

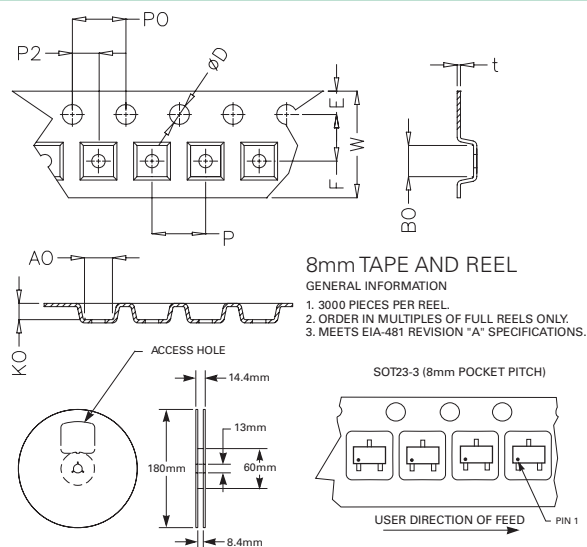


Package Dimensions — SOT23-3



Package	SOT23-3			
Pins	3			
JEDEC	TO-236			
	Millimeters		Inches	
	Min	Max	Min	Max
A	0.90	1.15	0.035	0.045
A1	0.00	0.10	0.000	0.004
b	0.30	0.51	0.012	0.020
c	0.08	0.20	0.003	0.008
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E1	1.20	1.40	0.047	0.055
e	0.95 BSC		0.038 BSC	
e1	1.90 BSC		0.075 BSC	
L	0.30	0.55	0.012	0.022
L1	0.25 BSC		0.010 BSC	
θ	0°	8°	0°	8°

Embossed Carrier Tape & Reel Specification — SOT23-3



Symbol	Millimeters		Inches	
	Min	Max	Min	Max
E	1.65	1.85	0.065	0.073
F	3.40	3.60	0.134	0.142
P2	1.90	2.10	0.075	0.083
D	1.40	1.60	0.055	0.063
P0	3.90	4.10	0.154	0.161
W	7.70	8.30	0.303	0.327
P	3.90	4.10	0.154	0.161
A0	3.05	3.25	0.120	0.128
B0	2.67	2.87	0.105	0.113
K0	1.12	1.32	0.044	0.052
t	0.22	0.24	0.009	0.009

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